MURA205T3G, MURA210T3G, SURA8210T3G

Preferred Devices

Surface Mount Ultrafast Power Rectifiers

Ideally suited for high voltage, high frequency rectification, or as free wheeling and protection diodes in surface mount applications where compact size and weight are critical to the system.

Features

- Small Compact Surface Mountable Package with J-Bend Leads
- Rectangular Package for Automated Handling
- High Temperature Glass Passivated Junction
- Low Forward Voltage Drop (0.74 V Max @ 2.0 A, $T_J = 150^{\circ}C$)
- AEC-Q101 Qualified and PPAP Capable
- SURA8 Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- All Packages are Pb-Free*

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 70 mg (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Polarity Band Indicates Cathode Lead
- ESD Protection:
 - ◆ Human Body Model > 4000 V (Class 3)
 - ◆ Machine Model > 400 V (Class C)



ON Semiconductor®

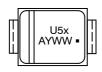
http://onsemi.com

ULTRAFAST RECTIFIERS 2 AMPERES, 50–100 VOLTS



SMA CASE 403D PLASTIC

MARKING DIAGRAM



U5x = Device Code

- x = A for MURA205T3
- = B for MURA210T3
- Assembly Location
- = Year
- WW = Work Week
- = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]
MURA205T3G	SMA (Pb-Free)	5,000/Tape & Reel
MURA210T3G	SMA (Pb-Free)	5,000/Tape & Reel
SURA8210T3G	SMA (Pb-Free)	5,000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MURA205T3G, MURA210T3G, SURA8210T3G

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage MURA205T3G MURA210T3G/SURA8210T3G	V _{RRM} V _{RWM} V _R	50 100	V
Average Rectified Forward Current @ $T_L = 155^{\circ}C$ @ $T_L = 135^{\circ}C$	I _{F(AV)}	1.0 2.0	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	50	A
Operating Junction Temperature Range	TJ	-65 to +175	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Lead ($T_L = 25^{\circ}C$) (Note 1)	Psi _{JL} (Note 2)	24	°C/W
Thermal Resistance, Junction-to-Ambient (Note 1)	R _{0JA}	216	

1. Rating applies when surface mounted on the minimum pad size recommended, PC Board FR-4.

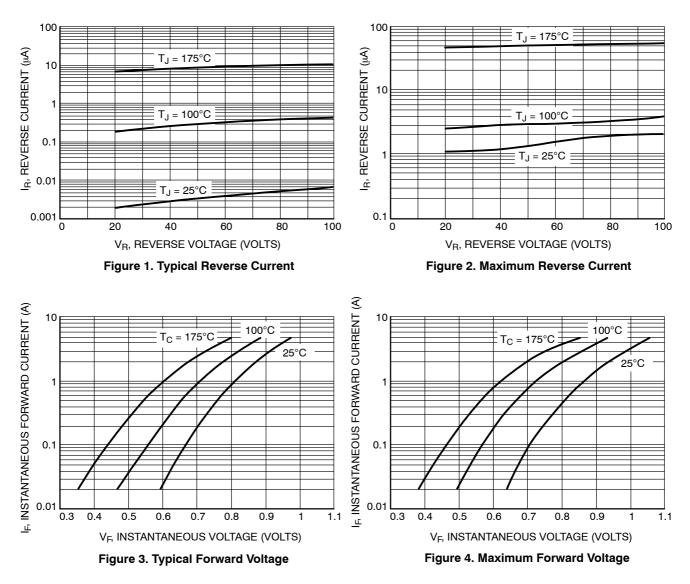
2. In compliance with JEDEC 51, these values (historically represented by R_{0JL}) are now referenced as Psi_{JL}.

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Maximum Instantaneous Forward Voltage (Note 3) ($i_F = 2.0 \text{ A}, T_J = 25^{\circ}\text{C}$) ($i_F = 2.0 \text{ A}, T_J = 150^{\circ}\text{C}$)	v _F	0.94 0.74	V
Maximum Instantaneous Reverse Current (Note 3) (Rated DC Voltage, $T_J = 25^{\circ}$ C) (Rated DC Voltage, $T_J = 150^{\circ}$ C)	İR	2.0 50	μΑ
Maximum Reverse Recovery Time ($i_F = 1.0 \text{ A}$, di/dt = 50 A/ μ s)	t _{rr}	30	ns

3. Pulse Test: Pulse Width = 300 μ s, Duty Cycle < 2.0%.

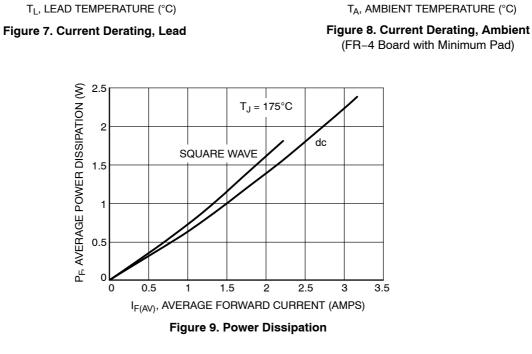
MURA205T3G, MURA210T3G, SURA8210T3G



NOTE: MAXIMUM CAPACITANCE AT NOTE: TYPICAL 0 V = 48 pF C, CAPACITANCE (pF) C, CAPACITANCE (pF) CAPACITANCE AT 0 V = 45 pF V_R, REVERSE VOLTAGE (VOLTS) V_R, REVERSE VOLTAGE (VOLTS) Figure 5. Typical Capacitance Figure 6. Maximum Capacitance I_{F(AV)}, AVERAGE FORWARD CURRENT (A) 1.5 IF, AVERAGE FORWARD CURRENT (A) $R_{\theta JL} = 24^{\circ}C/W$ $R_{\theta JA} = 216^{\circ}C/W$ 3.5 T_J = 175°C dc T_J = 175°C dc 2.5 SQUARE WAVE SQUARE WAVE

0.5

MURA205T3G, MURA210T3G, SURA8210T3G



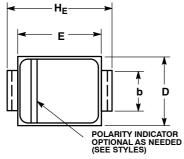
1.5

0.5

MURA205T3G, MURA210T3G, SURA8210T3G

PACKAGE DIMENSIONS

SMA CASE 403D-02 **ISSUE F**





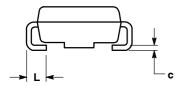
STYLE 1:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

PIN 1. CATHODE (POLARITY BAND) 2. ANODE

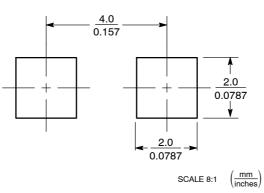
403D-01 OBSOLETE, NEW STANDARD IS 403D-02. З.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.97	2.10	2.20	0.078	0.083	0.087
A1	0.05	0.10	0.15	0.002	0.004	0.006
b	1.27	1.45	1.63	0.050	0.057	0.064
С	0.15	0.28	0.41	0.006	0.011	0.016
D	2.29	2.60	2.92	0.090	0.103	0.115
Е	4.06	4.32	4.57	0.160	0.170	0.180
HE	4.83	5.21	5.59	0.190	0.205	0.220
L	0.76	1.14	1.52	0.030	0.045	0.060





SOI DEBING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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MURA205T3/D